Plastic Medium-Power Complementary Silicon Transistors

These devices are designed for general-purpose amplifier and low-speed switching applications.



• High DC Current Gain -

 $h_{FE} = 2500 \text{ (Typ)} @ I_C = 4.0 \text{ Adc}$

• Collector Emitter Sustaining Voltage - @ 100 mAdc

V_{CEO(sus)} = 80 Vdc (Min) - BDX53B, 54B = 100 Vdc (Min) - BDX53C, 54C

• Low Collector-Emitter Saturation Voltage -

 $V_{CE(sat)} = 2.0 \text{ Vdc (Max)} @ I_C = 3.0 \text{ Adc}$ = 4.0 Vdc (Max) @ $I_C = 5.0 \text{ Adc}$

- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating A / \ A /	Syr lb l	V alue	Unit
Collector-Emitter College BDX53B, BDX54B BDX53C, BDX54C	V _C <u>E</u> (80 100	Vdø
Collector-Base Voltage BDX53B, BDX54B BDX53C, BDX54C	V _{CB}	80 100	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current - Continuous - Peak	I _C	8.0 12	Adc
Base Current	Ι _Β	0.2	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	65 0.48	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	70	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.92	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



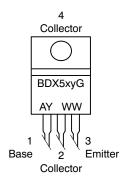
ON Semiconductor®

http://onsemi.com

DARLINGTON
8 AMPERE
COMPLEMENTARY SILICON
POWER TRANSISTORS
80-100 VOLTS, 65 WATTS



MARKING DIAGRAM & PIN ASSIGNMENT



BDX5xy = Device Code x = 3 or 4

y = B or C = Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

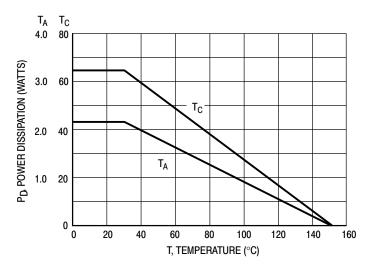


Figure 1. Power Derating

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					-
Collector-Emitter Sustaining Voltage (Note 1) (I _C = 100 mAdc, I _B = 0)	BDX53B, BDX54B BDX53C, BDX54C	V _{CEO(sus)}	80 100		Vdc
Collector Cutoff Current $(V_{CE} = 40 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 50 \text{ Vdc}, I_B = 0)$	BDX53B, BDX54B	I _{CEO}	Á	0.5 0.5	mAdc
Collector Cutoff Current (V _{CB} = 80 Vdu, I _E =)) (V _{CB} = 100 Vdc, I _E = 0)	EDX53B_BDX543 BDX53C, BDX54C		Ų	0.2 0.2	mAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I _C = 3.0 Adc, V _{CE} = 3.0 Vdc)		h _{FE}	750	-	-
Collector-Emitter Saturation Voltage (I _C = 3.0 Adc, I _B = 12 mAdc)		V _{CE(sat)}	-	2.0 4.0	Vdc
Base-Emitter Saturation Voltage (I _C = 3.0 Adc, I _C = 12 mA)		V _{BE(sat)}	-	2.5	Vdc
DYNAMIC CHARACTERISTICS					
Small-Signal Current Gain (I _C = 3.0 Adc, V _{CE} = 4.0 Vdc, f = 1.0 MHz)		h _{fe}	4.0	-	-
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	BDX53B, 53C BDX54B, 54C	C _{ob}	-	300 200	pF

^{1.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

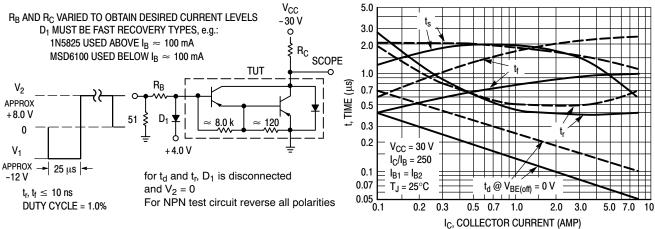


Figure 2. Switching Time Test Circuit

Figure 3. Switching Times

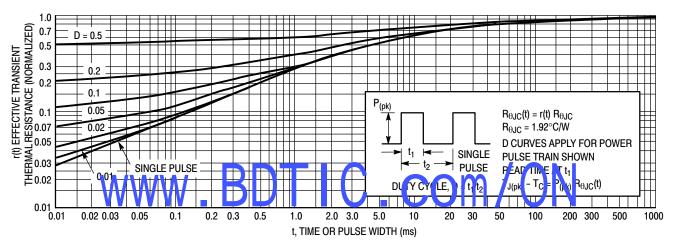


Figure 4. Thermal Response

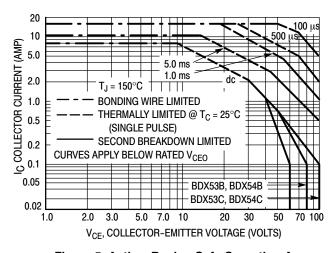


Figure 5. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150$ °C; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150$ °C. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

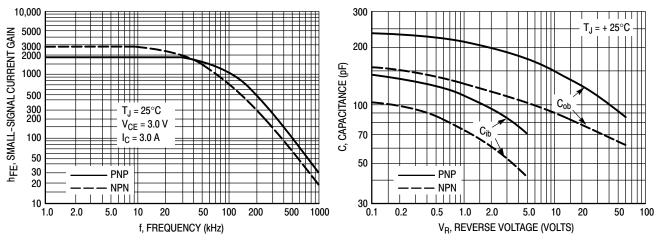


Figure 6. Small-Signal Current Gain

Figure 7. Capacitance

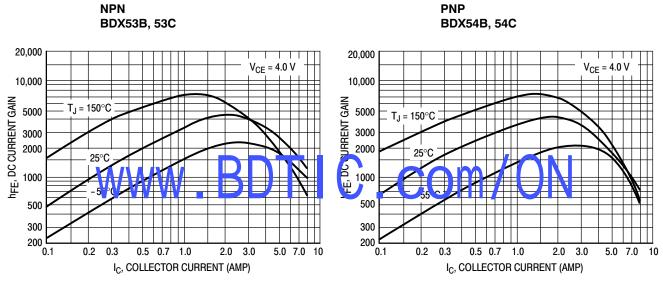


Figure 8. DC Current Gain

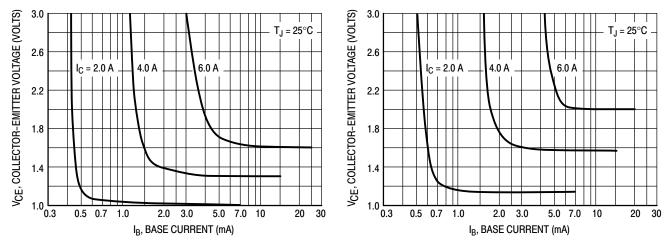


Figure 9. Collector Saturation Region

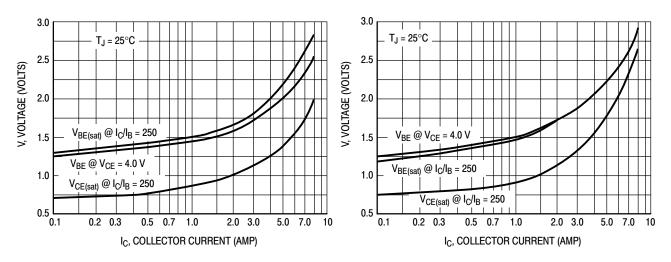


Figure 10. "On" Voltages

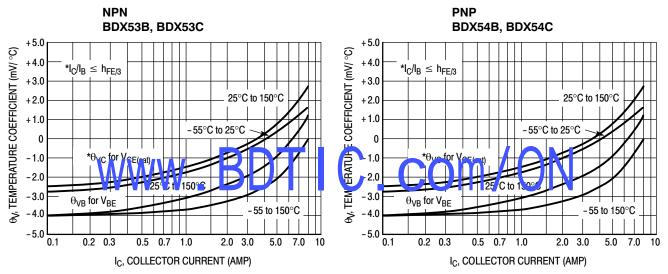


Figure 11. Temperature Coefficients

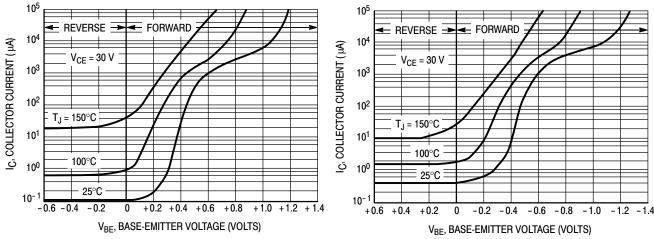
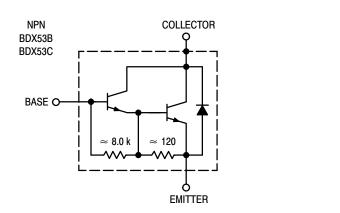


Figure 12. Collector Cut-Off Region



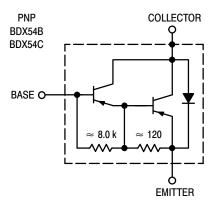


Figure 13. Darlington Schematic

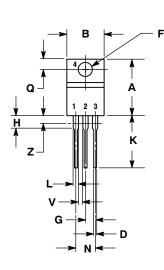
ORDERING INFORMATION

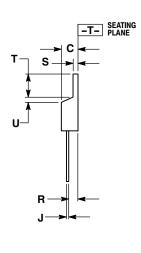
Device	Package	Shipping [†]	
BDX53B	TO-220		
BDX53BG	TO-220 (Pb-Free)	50 Units / Rail	
BDX53C	TO-220		
BDX53CG	TO-220 (Pb-Free)	50 Units / Rail	
BDX54B BDX54BG	TO -220	0 Uni s Atail	
BDA34BG	(Pb-Free)		
BDX54C	TO-220		
BDX54CG	TO-220 (Pb-Free)	50 Units / Rail	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 ISSUE AE





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

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